

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	N/A	860.7022m	N/A
RT2	N/A	1.2211	N/A
RT3	N/A	281.5873m	N/A
RT4	N/A	638.0161m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	N/A	201.6706m	N/A
CT2	N/A	29.7583m	N/A
CT3	N/A	1.3457m	N/A
CT4	N/A	8.9889m	N/A

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION

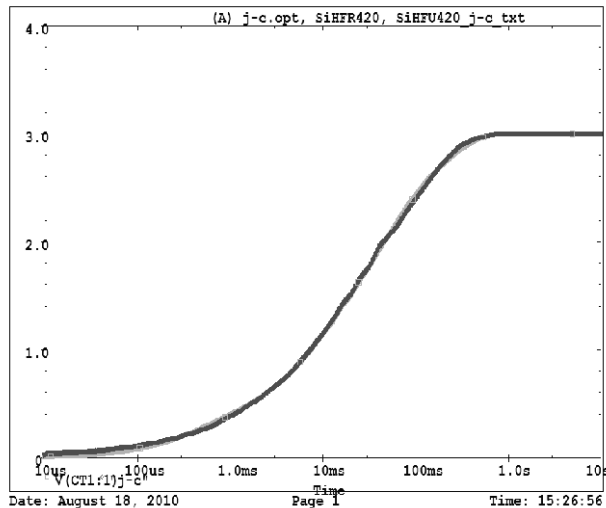
R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	N/A	355.5212m	N/A
RF2	N/A	1.1735	N/A
RF3	N/A	1.2515	N/A
RF4	N/A	218.7014m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	N/A	979.9360u	N/A
CF2	N/A	6.0701m	N/A
CF3	N/A	45.5053m	N/A
CF4	N/A	807.9194m	N/A

Note

N/A indicates not applicable



SiHFR420, SiHFU420 Tank j-c Temperature: 27.0



SiHFR420, SiHFU420 Filter j-c Temperature: 27.0

